Wannier functions

Macroscopic polarization (Berry phase) and related properties

#### Effective band structure of alloys P.Blaha (from Oleg Rubel, McMaster Univ, Canada)





#### Wannier functions



#### WANNIER90

Wannier90: A Tool for Obtaining Maximally-Localised Wannier Functions
A. A. Mostofi, J. R. Yates, Y.-S. Lee, I. Souza, D.
Vanderbilt and N. Marzari
Comput. Phys. Commun. 178, 685 (2008)
[http://wannier.org]

#### Bloch vs Wannier functions



# Max. localized Wannier functions (MLWF)



#### maximally localized wannier functions

- choose U(k) to minimize spread → MLWF
- total spread  $\Omega = \Omega_{I} + \widetilde{\Omega}$  can be split into gauge-invariant part and rest



- 🛶 minimize Ω̃
  - wannier90 computes U(k) in this way

[Marzari et al., Rev. Mod. Phys. 84, 1419 (2012)] http://wannier.org

wien2wannier provides interface to Wien2k

[Kuneš, Wissgott et al., Comp. Phys. Commun. 181, 1888]

# **Two flavours of Wannier functions**



# **MLWF:** applications

- analysis of chemical bonding bonding and antibonding states
- electric polarization and orbital magnetization BerryPi (O.Rubel et al.)
- Wannier interpolation (eg. Woptic, transport, ...)  $H(k)|_{\kappa} \xrightarrow{F} H(R)|_{\kappa^{-1}} \xrightarrow{F^{-1}} H(k)|_{G}$
- building effective hamiltonian tight binding parameters input for dynamical mean field theory

#### Wannier functions as a tight-binding basis (atom centered FW)



#### **Band structure**



- + original Wien2k band structure
- Band structure computed from Wannier hamiltonian

#### Disentanglement



 Band structure computed from Wannier hamiltonian Souza et al.: PRB 65, 035109 (2001)

# Relation to polarization (bond centered WF)

#### Bond-centered WF

Si





GaAs



symmetric (non-polar)

non-symmetric (polar)

$$\mathbf{P} = \frac{\mathbf{r}}{V} \left( \sum_{r} \mathbf{Z} \cdot \mathbf{r}_{r} = \sum_{n} \mathbf{r}_{n} \right)$$
  
Ionic part Electronic part

<u>King-Smith</u> & <u>Vanderbilt</u>, Phys. Rev. B 47, 1651 (1993)

# Workflow







- Regular SCF calculation
- Band structure plot
- Initialize wien2wannier (init\_w2w):
  - select bands, init. projections, # of WF (case.inwf file)
  - projected band structure "bands\_plot\_project" (case.win file)
  - additional options related to entanglement (case.win file)
- Compute overlap matrix element S<sub>mn</sub> and projections M<sub>mn</sub> (x w2w)
- Perform Wannierization (x wannier90):
  - position of Wannier centers and spreads (case.wout file)
  - Wannier hamiltonian (case\_hr.dat file)
- Initialize plotting, select plotting range, r-mesh (write\_inwplot)
- Evaluate WF on the r-mesh selected (x wplot)
- Convert the output of wplot into xcrysden format for plotting (wplot2xsf)
  - Plot WF

#### Useful resources

- Jan Kuneš *et al.* "Wien2wannier: From linearized augmented plane waves to maximally localized Wannier functions", Comp. Phys. Commun. 181, 1888 (2010).
- Wien2Wannier home and user guide: <u>http://www.ifp.tuwien.ac.at/forschung/arbeitsgrupp</u> <u>en/cms/software-download/wien2wannier/</u>
- Wannier90 home and user guide: <u>http://www.wannier.org</u>/
- Nicola Marzari *et al.* "Maximally localized Wannier functions: Theory and applications", Rev. Mod. Phys. 84, 1419 (2012)

# Macroscopic polarization



# + BerryPl

# Material properties related to polarization

#### **Piezo- and Ferroelectricity**



Effective charge



#### **Dielectric screening**



#### Pyroelectricity



#### What is polarization?



We will now assume that in each atom there are charges q separated by a distance  $\delta$ , so that  $q\delta$  is the dipole moment per atom. (We use  $\delta$  because we are already using d for the plate separation.) If there are N atoms per unit volume, there will be a *dipole moment per unit volume* equal to  $Nq\delta$ . This dipole moment per unit volume will be represented by a vector, P. Needless to say, it is in the direction of the individual dipole moments, i.e., in the direction of the charge





#### Polarization for periodic solids is undefined

# Modern theory of polarization

Pioneered by King-Smith, David Vanderbilt and Raffaele Resta

 $\Delta \mathbf{P} = \mathbf{P}^{(0)}$ 

 $\mathbf{P}^{(1)}$ 

All measurable physical quantities are related to the change in polarization!



#### **Components of polarization**



King-Smith and David Vanderbilt, Phys. Rev. B 47, 1651 (199

#### Berry phase

$$\mathrm{d}\varphi_n = -i \langle u_{n\mathbf{k}} | \nabla_{\mathbf{k}} | u_{n\mathbf{k}} \rangle \cdot \mathrm{d}\mathbf{k} = -i \ln \langle u_{n\mathbf{k}} | u_{n(\mathbf{k} - \mathrm{d}\mathbf{k})} \rangle.$$

 $\mathbf{S}_{mn}(\mathbf{k}_j, \mathbf{k}_{j+1}) = \langle u_{m\mathbf{k}_j} | u_{n\mathbf{k}_{j+1}} \rangle$  WIEN2WANNIER

$$\varphi(\mathbf{k}_{\parallel}) = 2 \operatorname{Im} \left[ \ln \prod_{j=0}^{J-1} \det \mathbf{S}_{M \times M}(\mathbf{k}_{j}, \mathbf{k}_{j+1}) \right]$$

$$arphi_{\mathrm{el},lpha} = S_{\perp}^{-1} \int_{S_{\perp}} \mathrm{d}S_{\perp} \; arphi(\mathbf{k}_{\parallel})$$

$$P_{\alpha} = \frac{e(\varphi_{\mathrm{el},\alpha} + \varphi_{\mathrm{ion},\alpha})}{2\pi\Omega} R_{\alpha}$$

King-Smith and David Vanderbilt, Phys. Rev. B 47, 1651 (1993)

#### Uncertainties



$$P_{\alpha} = \frac{e(\varphi_{\mathrm{el},\alpha} + \varphi_{\mathrm{ion},\alpha})}{2\pi\Omega} R_{\alpha}$$

$$\Delta \mathbf{P} = \mathbf{P}^{(0)} - \mathbf{P}^{(1)} \pm \frac{e}{\Omega} \mathbf{R}$$

 it is challenging to determine large polarization difference ~1 C/m<sup>2</sup>

Solution:  $\lambda_0 \Rightarrow \lambda_{1/2} \Rightarrow \lambda_1$ 

### **BerryPI** workflow

Need wien2k, wien2wannier, python 2.7.x and numpy



Comput. Phys. Commun. 184, 647 (2013)

## Choice of a reference structure



- structure file <u>must</u> preserve the symmetry
- begin with the lowest symmetry ( $\lambda_1$ ) case
- copy case  $\lambda_1$  to case  $\lambda_0$
- edit structure file for case  $\lambda_0$
- do <u>not</u> initialize calculation (init\_lapw)
- update density (x dstart)
- run SCF cycle (run[sp]\_lapw [-so -orb])
- run BerryPI

#### **Demonstration: Effective charge of GaN**



$$Z^*_{s,ij} = rac{\Omega}{e} \, rac{\Delta P_i}{\Delta r_{s,j}}$$

 $\varphi = \varphi_{\rm el} + \varphi_{\rm ion}$ 

**General definition** 

$$egin{aligned} &\Delta arphi &= arphi( ext{perturbed}) - arphi( ext{unperturbed}) \ &Z^*_{s,ii} &= rac{\Delta arphi_i}{2\pi \Delta u_{s,i}} & ext{"Shortcut" (i=j, no volume change)} \end{aligned}$$

Gan 2t calculation 80 Pel (0) = -0.1538 \$\overline(0) = -1.502 Pel(1) = -0.2509 Pion(1) = -1.4451 $\Phi_{tot} \neq (0) = -1.6618$  $\Phi_{++}(1) = -1.6960$  $\Delta \Phi (0 \rightarrow 4) = -1.6960 + 1.6618$ = -0.0342 $\Delta U = 0.001 - 0 = 0.001$  $\Delta \Phi$ Z\* Ξ 2V. SU. H# of atoms moved = -2.72

#### Reality check

GaN: effective charge, dielectric constants - Springer link.springer.com/content/pdf/10.1007%2F978-3-642-14148-5\_230.pdf by D Strauch - 2011 - Related articles gallium nitride (GaN) property: effective charge, dielectric constants (lattice properties). Born effective charge (wurtzite structure). Physical. Property. Numerical. You've visited this page 2 times. Last visit: 04/06/16

#### GaN: effective charge, dielectric constants

substance:	gallium nitride (GaN)
property:	effective charge, dielectric constants (lattice properties)

#### Born effective charge (wurtzite structure)

Physical Property	Numerical Values	Remarks	Ref.
Z*	2.73(3)	from LO-TO splitting, Raman scattering from bulk GaN	01G
	2.51	ab initio DFT(LDA) calculation	01Z
	2.67	ab initio DFT(GGA) calculation	
$Z_{xx}^*$	2.60	ab initio DFT(LDA) calculation	02W
Z22*	2.74		
$Z_{\mathrm{B,xx}}$ *	1.14	$Z_{\mathbf{B},ij}^{*} = Z_{ii}^{*} / \sqrt{\varepsilon_{\infty,ii}}$	
$Z_{B,zz}^{*}$	1.18		
$Z_{xx}^*$	2.51	ab-initio DFT(LDA) calculation	06S
Z <sub>22</sub> *	2.75		

#### Useful resources

- Sheikh J. Ahmed *et al.* "BerryPI: A software for studying polarization of crystalline solids with WIEN2k density functional all-electron package", Comp. Phys. Commun. 184, 647 (2013).
- BerryPI home and tutorials: <u>https://github.com/spichardo/BerryPI/wiki</u>
- Raffaele Resta "Macroscopic polarization in crystalline dielectrics: the geometric phase approach" Rev. Mod. Phys. 66, 899 (1994)
- Raffaele Resta and David Vanderbilt "Theory of Polarization: A Modern Approach" in *Physics of Ferroelectrics: a Modern Perspective* (Springer, 2007)

# Effective band structure of alloys



#### Semiconductor alloys





Thermoelectric: Si<sub>1-x</sub>Ge<sub>x</sub>

IR detector:

(HgCd)Te





Eg = 1 eV junction: (InGa)(NAs)





1.55 µm lasers: (InGa)As (InGa)(NAsSb) Ga(AsBi)

#### **Band structure**



### Zone folding

The character of  $\Phi$  changes between  $\Gamma - X$  from bonding to anti-bonding



Doubling the unit cell  $\rightarrow$  halfs the BZ  $\rightarrow$  backfolding of X to  $\Gamma$ the wavefunction can still tell you if an eigenvalue was  $\Gamma$  or X

# Unfolding the first-principle band structure

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a,

#### Plane wave expansion

$$\Psi_{n,\mathbf{R}}(\mathbf{r}) = \sum_{\mathbf{G}} C_{n,\mathbf{R}}(\mathbf{G}) \, e^{i(\mathbf{G} + \mathbf{G}) \cdot \mathbf{r}}$$

Bloch spectral weight

$$id_{K}(\mathbf{k}) = \sum_{\mathbf{g}\in V} \left| C_{ij,\mathbf{K}}(\mathbf{k}+\mathbf{g}) 
ight|^{2}$$

Popescu & Zunger: Phys. Rev. Lett. 104, 236403 (2010)

Rubel et al. Phys. Rev. B 90, 115202 (2014)

#### I README.md

#### fold2Bloch

Unfolding of first-principle electronic band structure obtained with WIEN2k DFT-(L)APW code

Contributors:

- Anton Bokhanchuk
- Elias Assmann
- · Sheikh Jamil Ahmed · Oleg Rubel





# Workflow



- Construct primitive unit cell
- Make supercell (supercell)
- Run SCF calculation

**XCrySDen** 



- Create k-path (case.klist\_band file)
- Compute wave functions (case.vector[so] file) for the selected k-path:
  - x lapw1 [-p]
  - x lapwso [-p] (in the case of spin-orbit coupling)

# fold2Bloch

• Unfold band structure (fold2Bloch)



Plot effective band structure (ubs\_dots\*.m)

#### Demonstration: Band structure of $Si_{1-x}Ge_x$ alloy (x ~ 0.2)





#### Thermoelectric material: Si0.7Ge0.3



## (Hg,Cd)Te band structure evolution



#### Impact of alloying disorder on charge transport

 $CdTe \rightarrow (HgCd)Te$ 



$$\mu_h = 200 \rightarrow 10 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$$
  
 $\mu_e = 4,000 \rightarrow 2,500 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$ 

 $GaAs \rightarrow Ga(AsBi)$ 

 $\mu_e = 1,100 \rightarrow 1,000,000 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$ 

#### Useful resources

- V. Popescu and A. Zunger, Phys. Rev. Lett. 104, 236403 (2010).
- O. Rubel, A. Bokhanchuk, S. J. Ahmed, and E. Assmann "Unfolding the band structure of disordered solids: from bound states to highmobility Kane fermions" Phys. Rev. B 90, 115202 (2014)
- fold2Bloch home and tutorials: <u>https://github.com/rubel75/fold2Bloch</u>

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